TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74AC521P,TC74AC521F,TC74AC521FW

## 8-Bit Equality Comparator

Note: xxxFW (JEDEC SOP) is not available in Japan.

The TC74AC521 is an advanced high speed CMOS 8-BIT DIGITAL COMPARATOR fabricated with silicon gate and double-layer metal wiring $C^2MOS$ technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It compares two 8-bit binary or BCD words applied inputs $P_0$~$P_7$, and inputs $Q_0$~$Q_7$, and indicates whether or not they are equal.

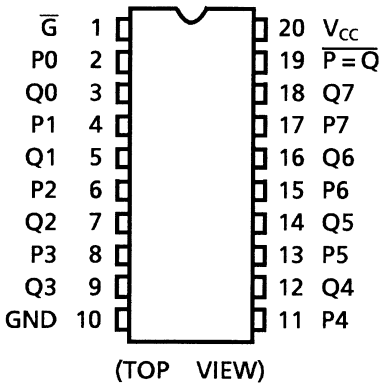
A signal active low enable is provided to facilitate cascading of several packages to compare of words greater than 8 bits.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

### Features

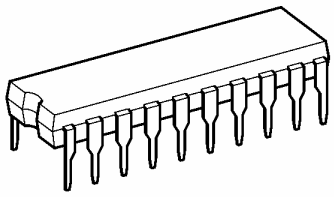
- High speed: $t_{pd}$ = 6.4 ns (typ.) at $V_{CC}$ = 5 V
- Low power dissipation: $I_{CC}$ = 8 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% $V_{CC}$ (min)
- Symmetrical output impedance: $|I_{OH}| = I_{OL}$ = 24 mA (min)
  Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC}$ (opr) = 2 to 5.5 V
- Pin and function compatible with 74F521

### Pin Assignment



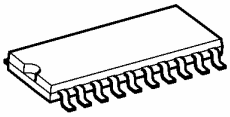
(TOP VIEW)

TC74AC521P

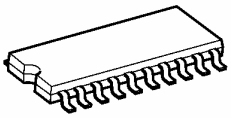


DIP20-P-300-2.54A

TC74AC521F

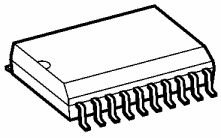


SOP20-P-300-1.27A



SOP20-P-300-1.27

TC74AC521FW

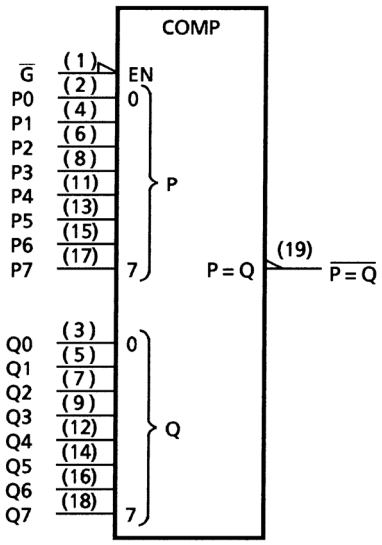


SOL20-P-300-1.27

Weight

| | |
|---|---|
| DIP20-P-300-2.54A | : 1.30 g (typ.) |
| SOP20-P-300-1.27A | : 0.22 g (typ.) |
| SOP20-P-300-1.27 | : 0.22 g (typ.) |
| SOL20-P-300-1.27 | : 0.46 g (typ.) |

## IEC Logic Symbol

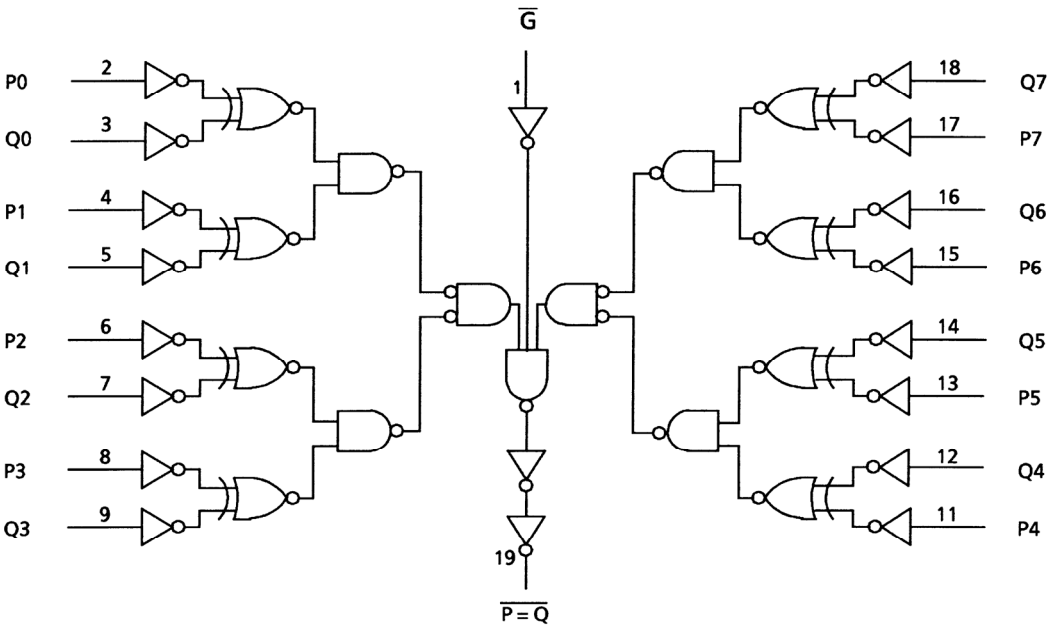



## Truth Table

| Inputs | | Output |
|---|---|---|
| P, Q | $\overline{G}$ | $\overline{P = Q}$ |
| P = Q | L | L |
| P ≠ Q | L | H |
| X | H | H |

X: Don't care

## System Diagram



## Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|---|---|---|---|
| Supply voltage range | $V_{CC}$ | −0.5 to 7.0 | V |
| DC input voltage | $V_{IN}$ | −0.5 to $V_{CC}$ + 0.5 | V |
| DC output voltage | $V_{OUT}$ | −0.5 to $V_{CC}$ + 0.5 | V |
| Input diode current | $I_{IK}$ | ±20 | mA |
| Output diode current | $I_{OK}$ | ±50 | mA |
| DC output current | $I_{OUT}$ | ±50 | mA |
| DC $V_{CC}$/ground current | $I_{CC}$ | ±100 | mA |
| Power dissipation | $P_D$ | 500 (DIP) (Note 2)/180 (SOP) | mW |
| Storage temperature | $T_{stg}$ | −65 to 150 | °C |

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = −40 to 65°C. From Ta = 65 to 85°C a derating factor of −10 mW/°C should be applied up to 300 mW.

## Recommended Operating Conditions (Note)

| Characteristics | Symbol | Rating | Unit |
|---|---|---|---|
| Supply voltage | $V_{CC}$ | 2.0 to 5.5 | V |
| Input voltage | $V_{IN}$ | 0 to $V_{CC}$ | V |
| Output voltage | $V_{OUT}$ | 0 to $V_{CC}$ | V |
| Operating temperature | $T_{opr}$ | −40 to 85 | °C |
| Input rise and fall time | dt/dV | 0 to 100 ($V_{CC}$ = 3.3 ± 0.3 V)<br>0 to 20 ($V_{CC}$ = 5 ± 0.5 V) | ns/V |

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

## Electrical Characteristics

### DC Characteristics

| Characteristics | Symbol | Test Condition | | $V_{CC}$ (V) | Ta = 25°C Min | Ta = 25°C Typ. | Ta = 25°C Max | Ta = −40 to 85°C Min | Ta = −40 to 85°C Max | Unit |
|---|---|---|---|---|---|---|---|---|---|---|
| High-level input voltage | $V_{IH}$ | — | | 2.0 | 1.50 | — | — | 1.50 | — | V |
| | | | | 3.0 | 2.10 | — | — | 2.10 | — | |
| | | | | 5.5 | 3.85 | — | — | 3.85 | — | |
| Low-level input voltage | $V_{IL}$ | — | | 2.0 | — | — | 0.50 | — | 0.50 | V |
| | | | | 3.0 | — | — | 0.90 | — | 0.90 | |
| | | | | 5.5 | — | — | 1.65 | — | 1.65 | |
| High-level output voltage | $V_{OH}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OH}$ = −50 μA | 2.0 | 1.9 | 2.0 | — | 1.9 | — | V |
| | | | | 3.0 | 2.9 | 3.0 | — | 2.9 | — | |
| | | | | 4.5 | 4.4 | 4.5 | — | 4.4 | — | |
| | | | $I_{OH}$ = −4 mA | 3.0 | 2.58 | — | — | 2.48 | — | |
| | | | $I_{OH}$ = −24 mA | 4.5 | 3.94 | — | — | 3.80 | — | |
| | | | $I_{OH}$ = −75 mA (Note) | 5.5 | — | — | — | 3.85 | — | |
| Low-level output voltage | $V_{OL}$ | $V_{IN}$ = $V_{IH}$ or $V_{IL}$ | $I_{OL}$ = 50 μA | 2.0 | — | 0.0 | 0.1 | — | 0.1 | V |
| | | | | 3.0 | — | 0.0 | 0.1 | — | 0.1 | |
| | | | | 4.5 | — | 0.0 | 0.1 | — | 0.1 | |
| | | | $I_{OL}$ = 12 mA | 3.0 | — | — | 0.36 | — | 0.44 | |
| | | | $I_{OL}$ = 24 mA | 4.5 | — | — | 0.36 | — | 0.44 | |
| | | | $I_{OL}$ = 75 mA (Note) | 5.5 | — | — | — | — | 1.65 | |
| Input leakage current | $I_{IN}$ | $V_{IN}$ = $V_{CC}$ or GND | | 5.5 | — | — | ±0.1 | — | ±1.0 | μA |
| Quiescent supply current | $I_{CC}$ | $V_{IN}$ = $V_{CC}$ or GND | | 5.5 | — | — | 8.0 | — | 80.0 | μA |

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

### AC Characteristics ($C_L$ = 50 pF, $R_L$ = 500 Ω, input: $t_r$ = $t_f$ = 3 ns)

| Characteristics | Symbol | Test Condition | $V_{CC}$ (V) | Ta = 25°C Min | Ta = 25°C Typ. | Ta = 25°C Max | Ta = −40 to 85°C Min | Ta = −40 to 85°C Max | Unit |
|---|---|---|---|---|---|---|---|---|---|
| Propagation delay time (Pn, Qn- $\overline{P=Q}$ ) | $t_{pLH}$ $t_{pHL}$ | — | 3.3 ± 0.3 | — | 10.5 | 17.5 | 1.0 | 20.0 | ns |
| | | | 5.0 ± 0.5 | — | 7.2 | 11.0 | 1.0 | 12.5 | |
| Propagation delay time ( $\overline{G}$ - $\overline{P=Q}$ ) | $t_{pLH}$ $t_{pHL}$ | — | 3.3 ± 0.3 | — | 7.2 | 11.5 | 1.0 | 13.0 | ns |
| | | | 5.0 ± 0.5 | — | 4.8 | 7.0 | 1.0 | 8.0 | |
| Input capacitance | $C_{IN}$ | — | | — | 5 | 10 | — | 10 | pF |
| Power dissipation capacitance | $C_{PD}$ (Note) | — | | — | 34 | — | — | — | pF |

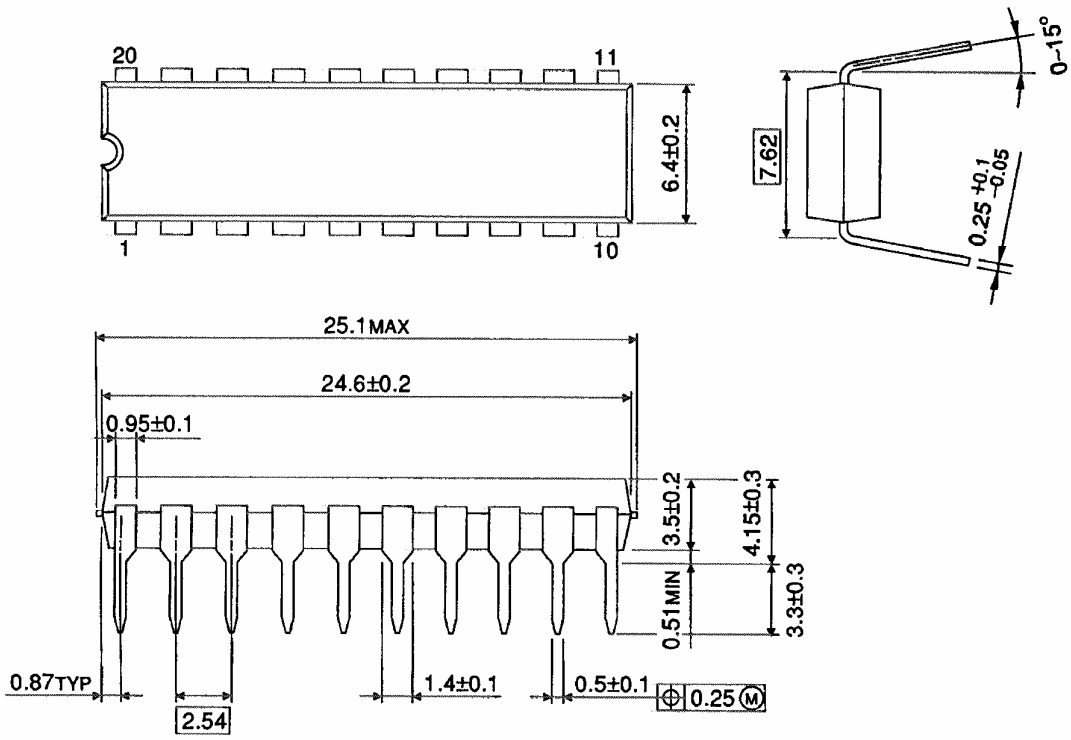
Note: $C_{PD}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}\ (opr) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## Package Dimensions

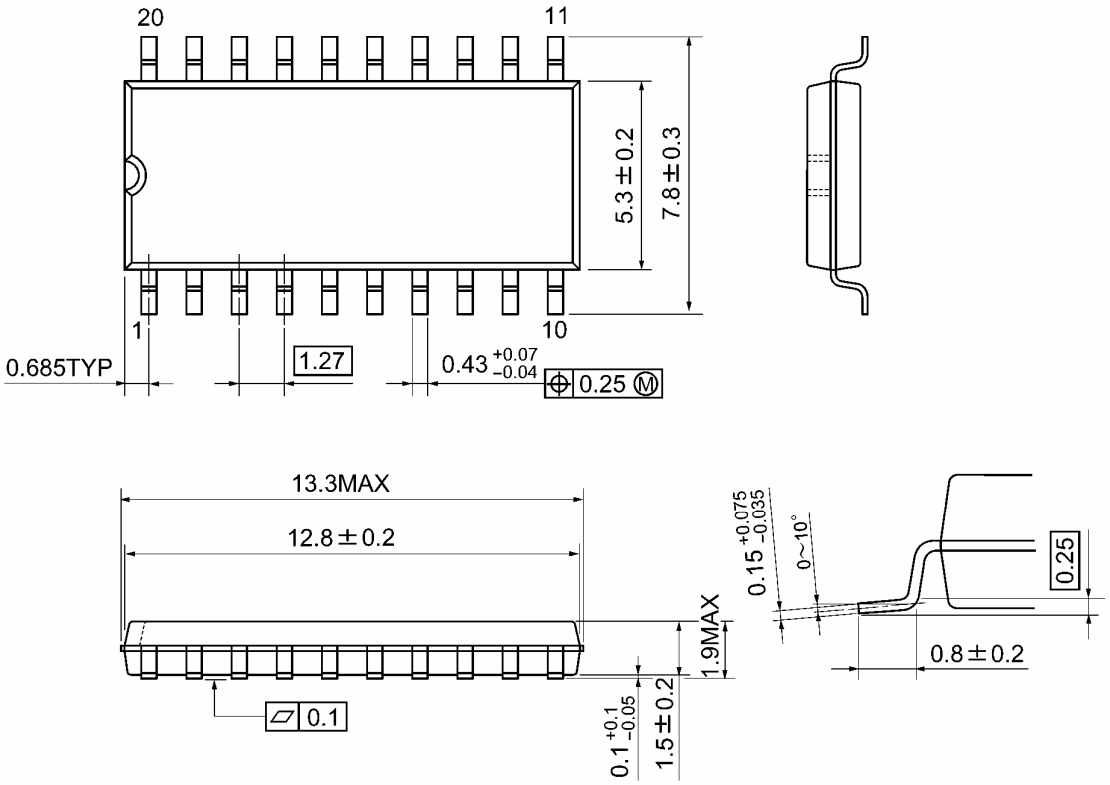
DIP20-P-300-2.54A Unit : mm




Weight: 1.30 g (typ.)

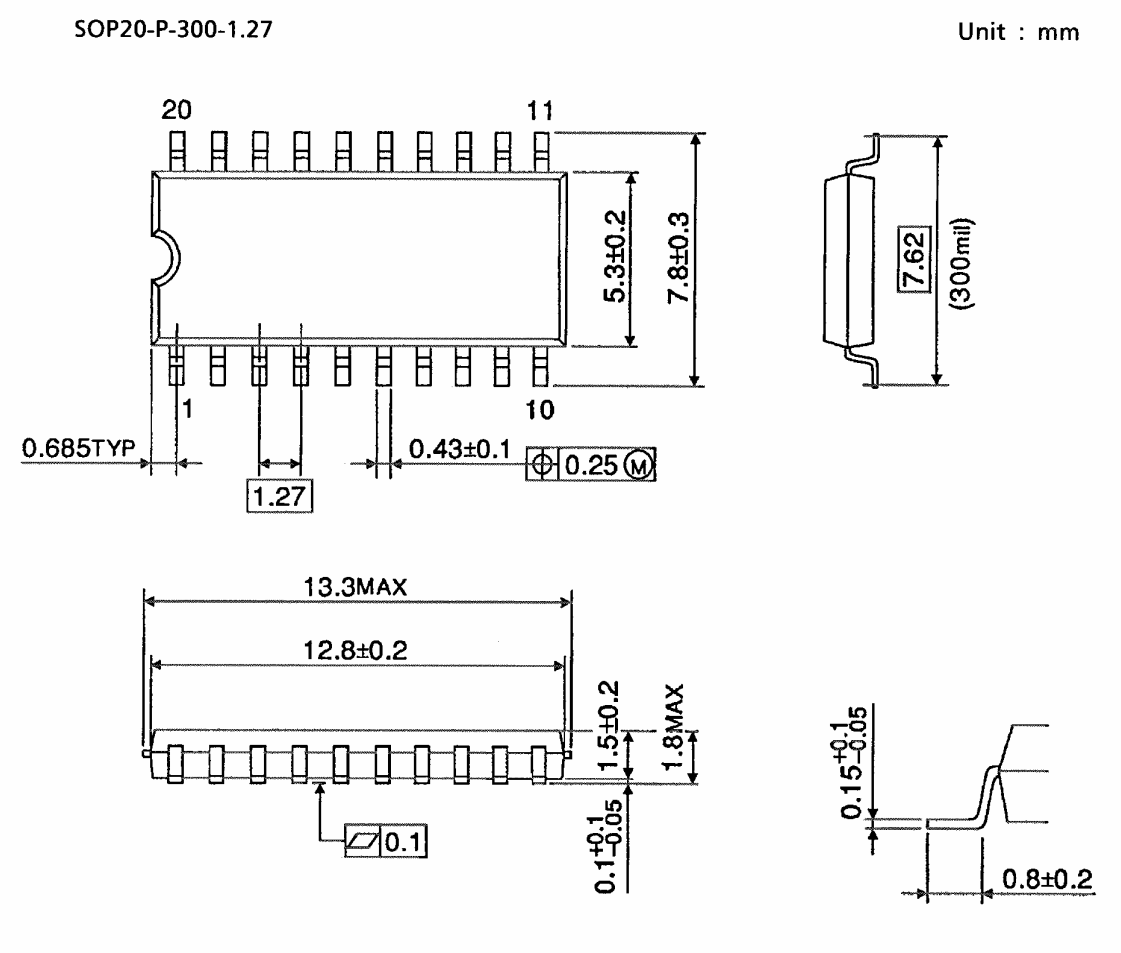
## Package Dimensions

SOP20-P-300-1.27A Unit: mm




Weight: 0.22 g (typ.)

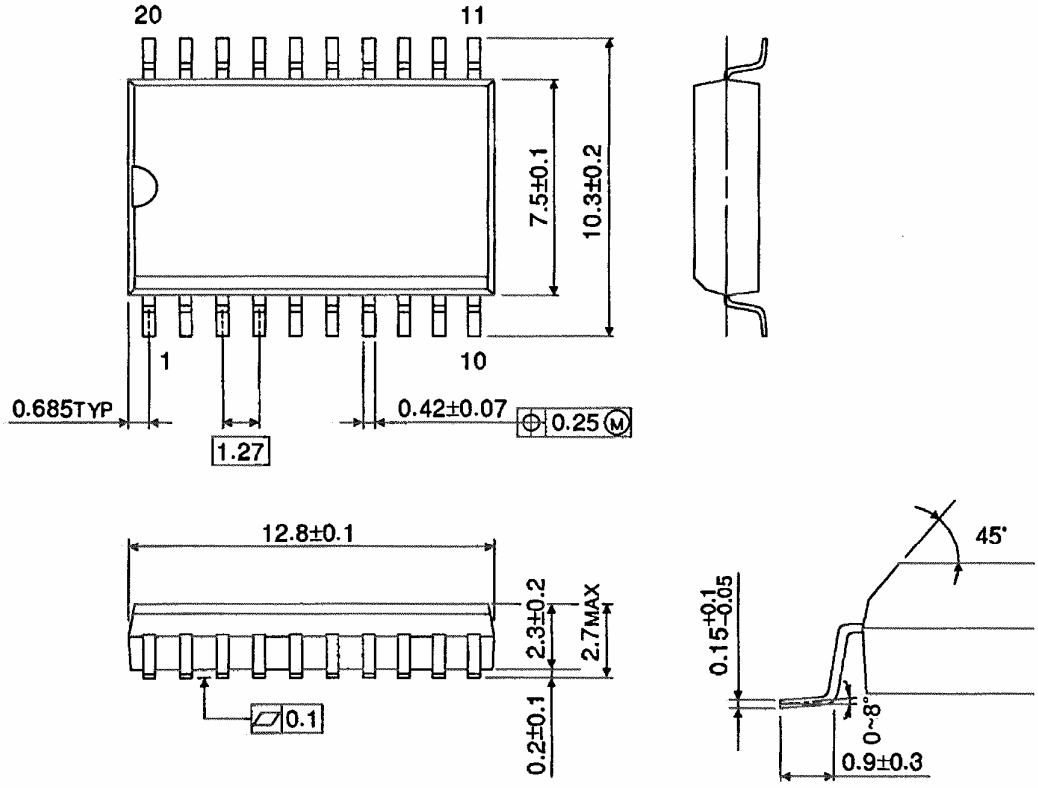
## Package Dimensions




Weight: 0.22 g (typ.)

## Package Dimensions (Note)

SOL20-P-300-1.27 Unit : mm




Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

**Note: Lead (Pb)-Free Packages**

**DIP20-P-300-2.54A SOP20-P-300-1.27A**

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